

Features

- Split Gate Trench MOSFET Technology
- High Density Cell Design for Low $R_{DS(ON)}$
- Excellent Package for Heat Dissipation
- Moisture Sensitivity Level 1
- Halogen Free. "Green" Device (Note 1)
- Epoxy Meets UL 94 V-0 Flammability Rating
- Lead Free Finish/RoHS Compliant ("P" Suffix Designates RoHS Compliant. See Ordering Information)

N-CHANNEL MOSFET

Maximum Ratings

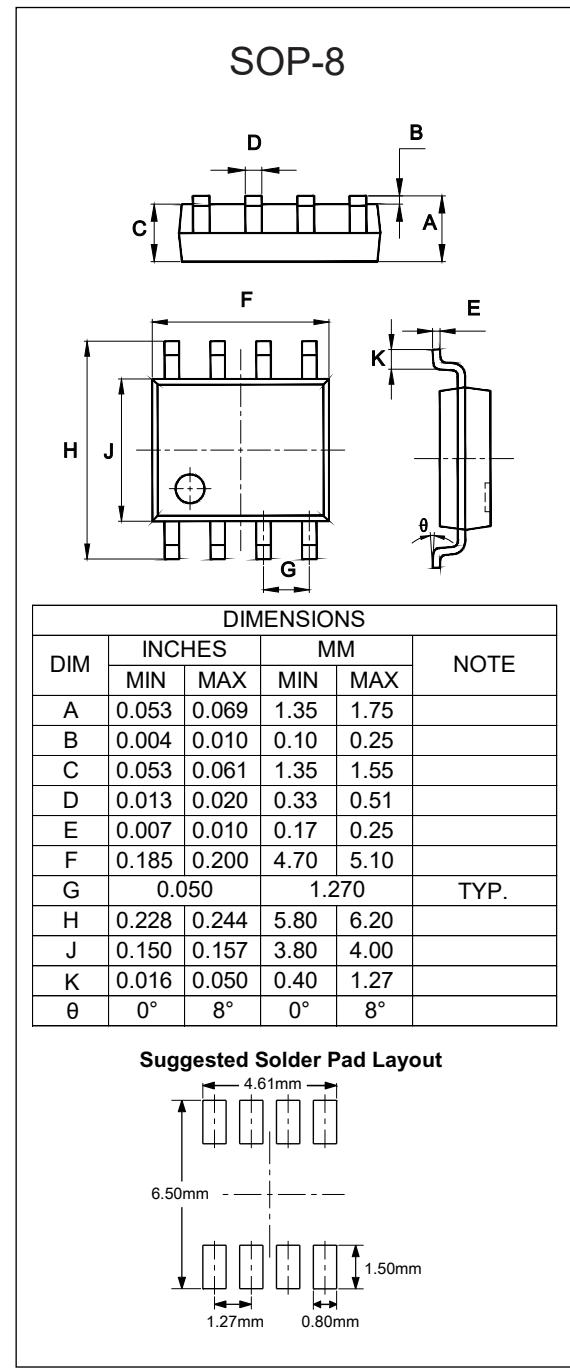
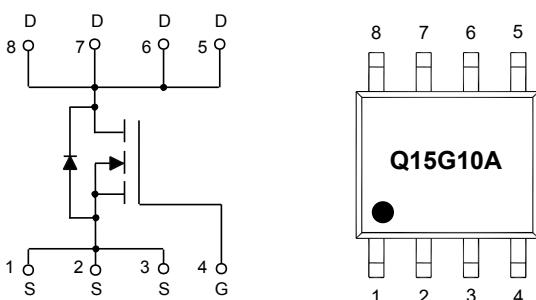
- Operating Junction Temperature Range : -55°C to +150°C
- Storage Temperature Range: -55°C to +150°C
- Thermal Resistance: 60°C/W Junction to Ambient(Steady-State) (Note 2)

Parameter	Symbol	Rating	Unit
Drain-Source Voltage	V_{DS}	100	V
Gate-Source Voltage	V_{GS}	± 20	V
Continuous Drain Current <small>$T_A=25^\circ C$</small>	I_D	15	A
		9.5	
Pulsed Drain Current (Note 3)	I_{DM}	60	A
Total Power Dissipation (Note 4)	P_D	2.1	W
Single Pulsed Avalanche Energy (Note 5)	E_{AS}	156	mJ

Note:

1. Halogen free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
2. The value of $R_{\theta JA}$ is measured with the device mounted on 1in² FR-4 board with 2oz. Copper, in a still air environment with $T_A = 25^\circ C$. The value in any given application depends on the user's specific board design.
3. Repetitive rating; pulse width limited by max. junction temperature.
4. PD is based on max. junction temperature, using Steady-State junction-ambient thermal resistance.
5. $T_J=25$, $V_{DD}=25V$, $V_{GS}=10V$, $L=0.5mH$.

Internal Structure and Marking Code



Electrical Characteristics @ 25°C (Unless Otherwise Specified)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Static Characteristics						
Drain-Source Breakdown Voltage	$V_{(BR)DSS}$	$V_{GS}=0V, I_D=250\mu A$	100			V
Gate-Source Leakage Current	I_{GSS}	$V_{DS}=0V, V_{GS}=\pm 20V$			± 100	nA
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS}=100V, V_{GS}=0V$			1	μA
Gate-Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}, I_D=250\mu A$	1	1.8	3	V
Drain-Source On-Resistance	$R_{DS(on)}$	$V_{GS}=10V, I_D=10A$		8	9.5	$m\Omega$
		$V_{GS}=4.5V, I_D=5A$		9.7	12.5	
Gate Resistance	R_g	f=1MHz, Open drain		0.68		Ω
Diode Characteristics						
Continuous Body Diode Current	I_S				15	A
Diode Forward Voltage	V_{SD}	$V_{GS}=0V, I_S=15A$			1.3	V
Reverse Recovery Time	t_{rr}	$I_S=10A, dI/dt=100A/\mu s$		50		ns
Reverse Recovery Charge	Q_{rr}			62		nC
Dynamic Characteristics						
Input Capacitance	C_{iss}	$V_{DS}=50V, V_{GS}=0V, f=1MHz$		2350		pF
Output Capacitance	C_{oss}			797		
Reverse Transfer Capacitance	C_{rss}			13		
Total Gate Charge	Q_g	$V_{DS}=50V, V_{GS}=10V, I_D=10A$		36		nC
Gate-Source Charge	Q_{gs}			5.8		
Gate-Drain Charge	Q_{gd}			5.6		
Turn-On Delay Time	$t_{d(on)}$	$V_{DD}=50V, V_{GS}=10V, R_{GEN}=2.2\Omega, I_D=10A$		10.8		ns
Turn-On Rise Time	t_r			4.4		
Turn-Off Delay Time	$t_{d(off)}$			27		
Turn-Off Fall Time	t_f			7		

Curve Characteristics

Fig. 1 - Typical Output Characteristics

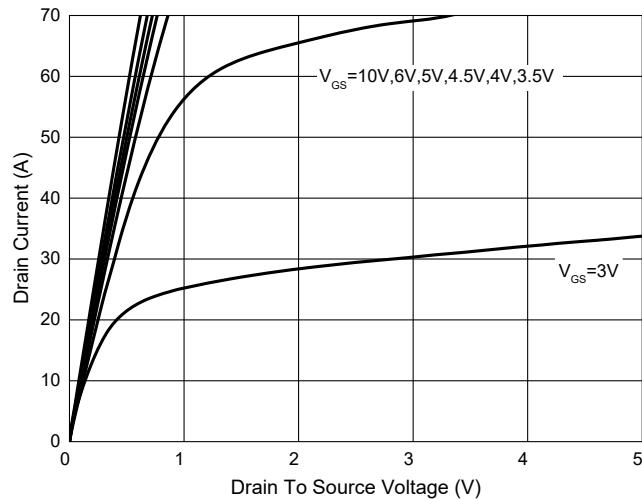


Fig. 2 - Transfer Characteristics

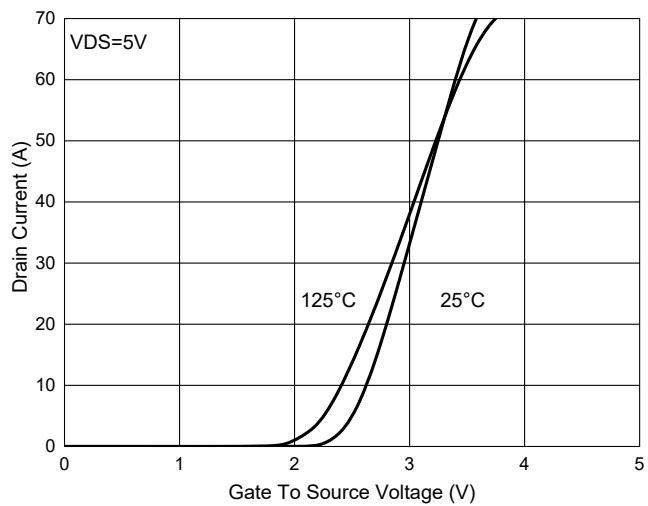


Fig. 3 - $R_{DS(ON)}$ — V_{GS}

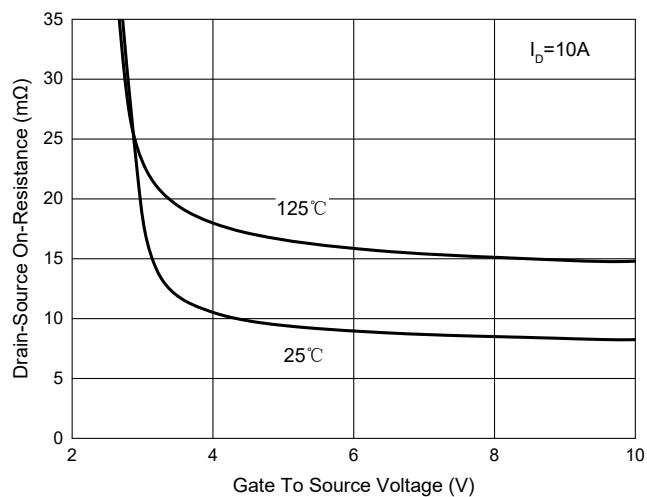


Fig. 4 - $R_{DS(ON)}$ — I_D

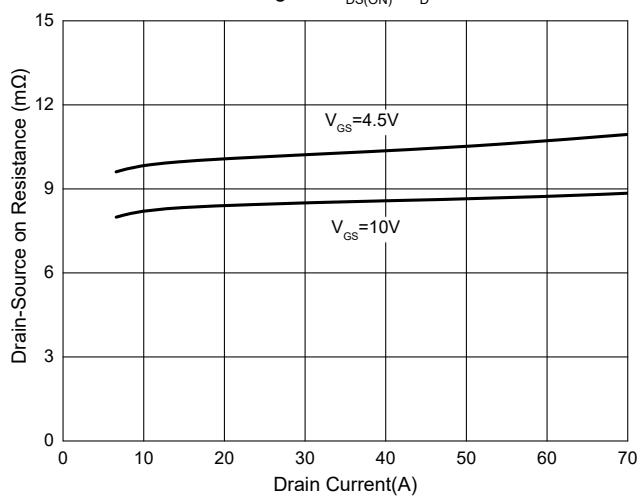


Fig. 5 - Capacitance Characteristics

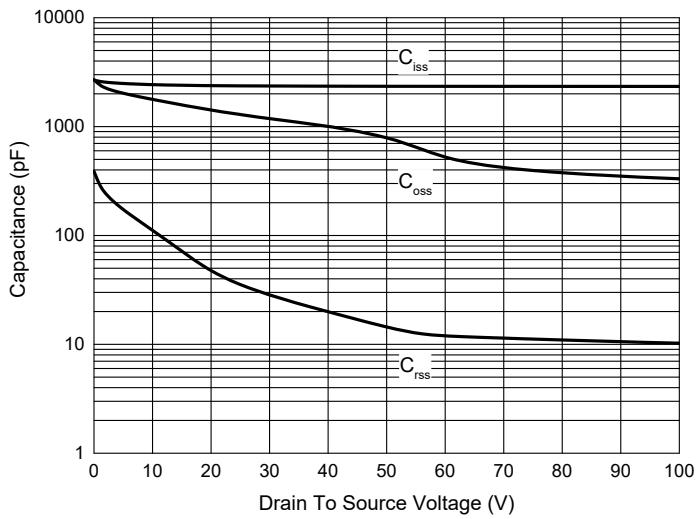
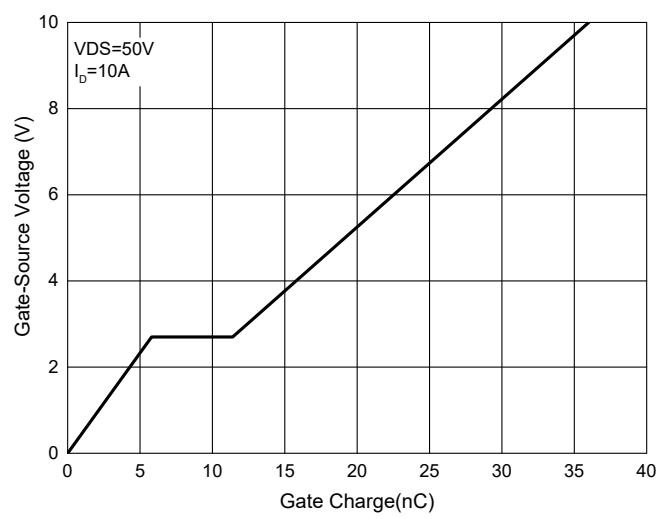


Fig. 6 - Gate Charge



Curve Characteristics

Fig. 7 - Normalized Threshold voltage

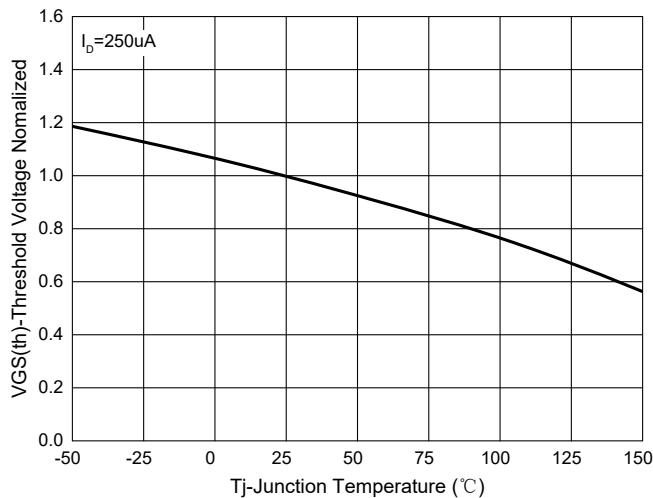


Fig. 8 - Normalized On Resistance Characteristics

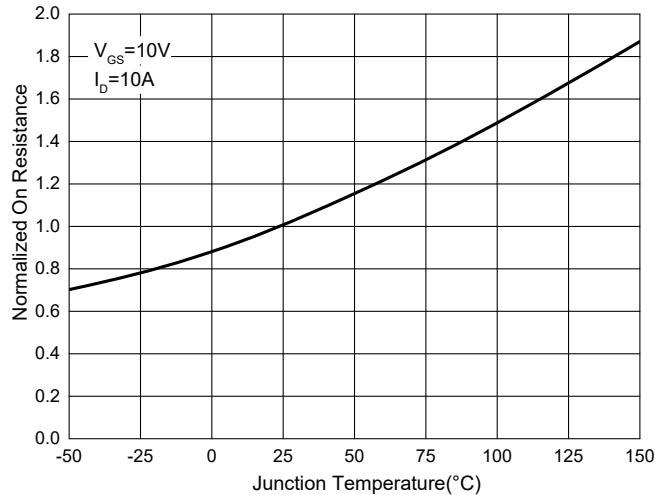


Fig. 9 - I_s — V_{SD}

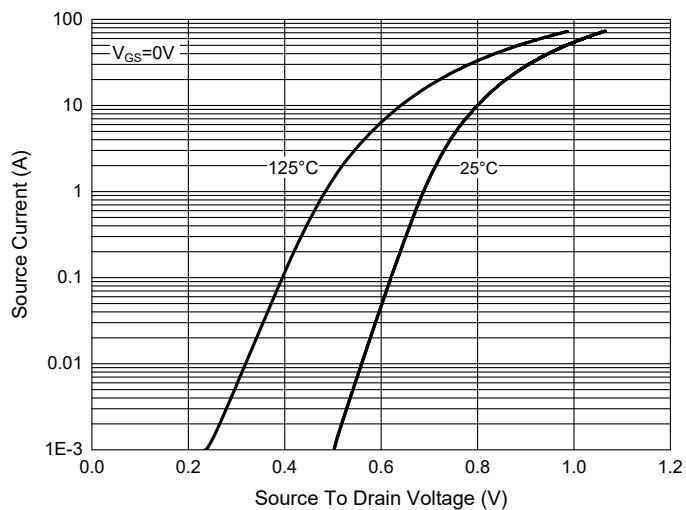


Fig. 10 - Drain Current

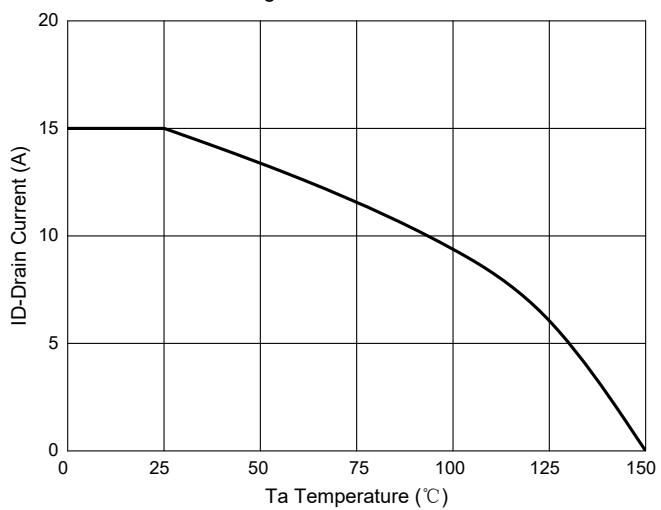
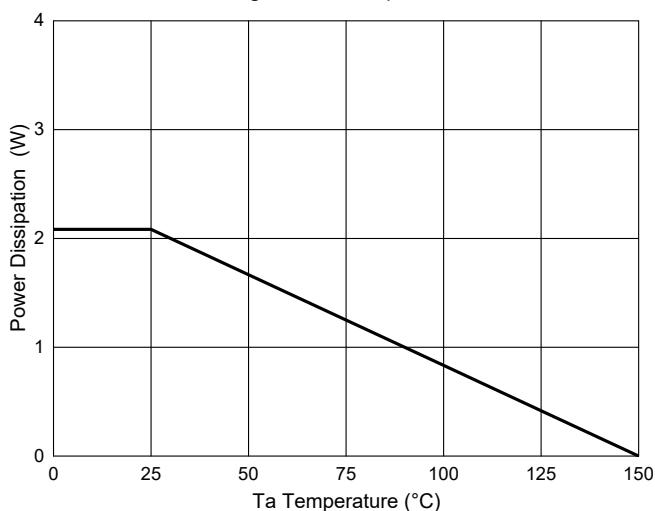


Fig.11-PD Dissipation



Curve Characteristics

Fig. 12 - Safe Operation Area

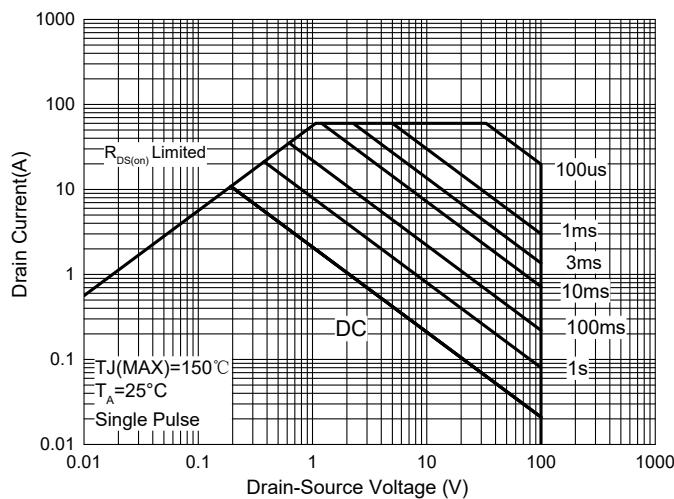
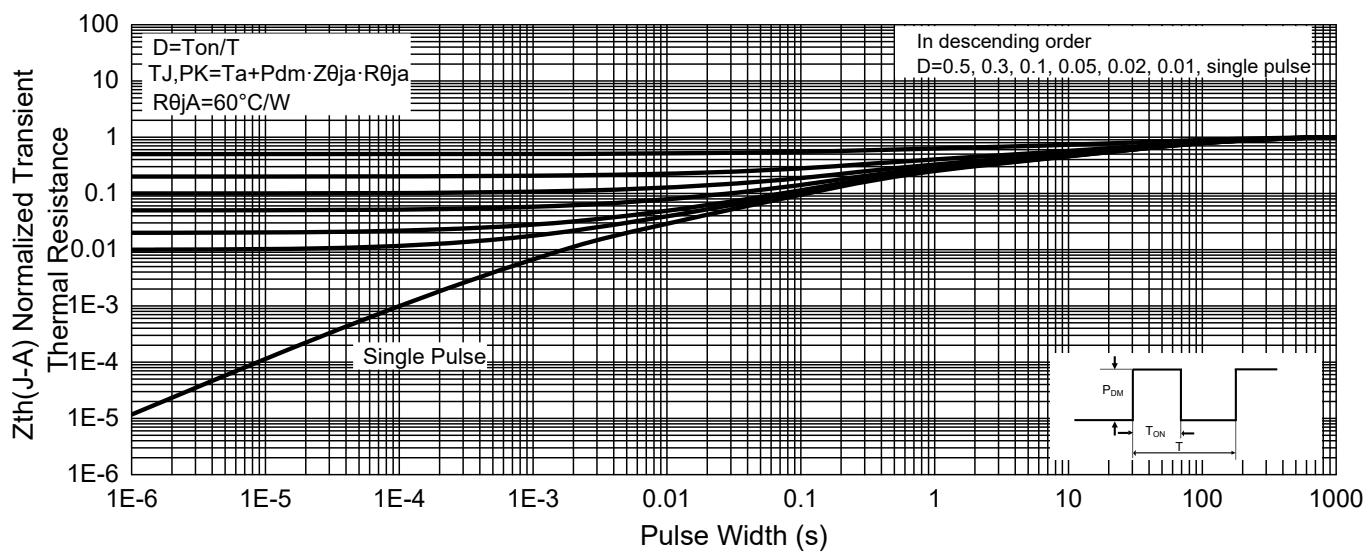


Fig. 13 -Normalized Transient Thermal Impedance



Ordering Information

Device	Packing
Part Number-TP	Tape&Reel: 4Kpcs/Reel

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